

UNISONIC TECHNOLOGIES CO., LTD

2SK3666 Preliminary JFET

N-CHANNEL JUNCTIN SILICON FET

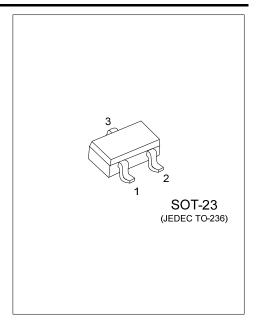
■ DESCRIPTION

The UTC **2SK3666** is an N-channel junctin silicon FET, it uses UTC's advanced technology to provide the customers with low $I_{\rm GSS}$ and low $C_{\rm RSS}$

The UTC **2SK3666** is suitable for low-frequency general-purpose amplifier, impedance conversion, infrared sensor applications.

■ FEATURES

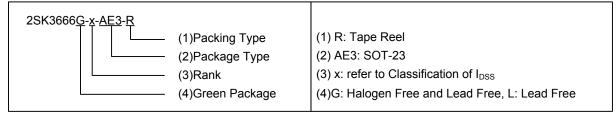
- * Low I_{GSS}
- * Low C_{RSS}



■ ORDERING INFORMATION

Ordering	Number	Dookogo	Pin	Assignn	Dealing		
Lead Free	Halogen Free	Package	1	2	3	Packing	
2SK3666L-x-AE3-R	2SK3666G-x-AE3-R	SOT-23	S	D	G	Tape Reel	

Note: Pin Assignment: S: Source D: Drain G: Gate



■ MARKING



■ **ABSOLUTE MAXIMUM RATINGS** (T_C=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DSS}	30	V
Gate-Drain Voltage		V_{GDS}	-30	V
Gate Current		I_{G}	10	mA
Drain Current	Continuous	I _D	10	mA
Power Dissipation		P _D	200	mW
Junction Temperature		T_J	+150	°C
Storage Temperature Range		T _{STG}	-55 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ **ELECTRICAL CHARACTERISTICS** (T_C=25°C, unless otherwise specified)

		-	_		_	_	
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
OFF CHARACTERISTICS							
Gate-Drain Breakdown Voltage	V _{(BR)GDS}	I _G =-10μA, V _{DS} =0V	-30			V	
Drain-Source Leakage Current	I _{DSS}	V _{DS} =10V, V _{GS} =0V	0.6		6.0	mA	
Gate-Source Leakage Current	I _{GSS}	V _{GS} =-20V, V _{DS} =0V			-1.0	nA	
Forward Transfer Admittance	yfs	V _{GS} =0V, V _{DS} =10V, f=1kHz	3.0	6.5		mS	
ON CHARACTERISTICS							
Cutoff Voltage	V _{GS(OFF)}	V_{DS} =10V, I_D =1 μ A	-0.18	-0.95	-2.2	V	
Static Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =0V, V _{DS} =10mV		270		Ω	
DYNAMIC PARAMETERS							
Input Capacitance	C _{ISS}	\/ -0\/ \/ -10\/ f=1 0MU=		4		pF	
Reverse Transfer Capacitance	C _{RSS}	V_{GS} =0V, V_{DS} =10V, f=1.0MHz	_	1.1		pF	

■ CLASSIFICATION OF I_{DSS}

RANK	2	3	4	
RANGE	0.6 ~ 1.5	1.2 ~ 3.0	2.5 ~ 6.0	

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